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Docket No. 740819-560

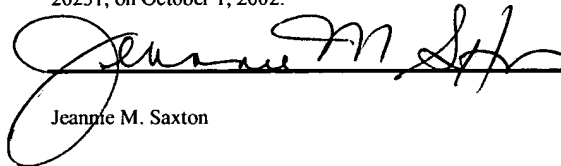
IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:)
Taiji NODA) Group Art Unit: 2829
Serial No. 09/865,546) Examiner: Asok K. SARKAR
Filed: May 29, 2001)
For: SEMICONDUCTOR DEVICE HAVING) Date: October 1, 2002
DIFFUSION LAYER FORMED USING)
DOPANT OF LARGE MASS NUMBER)
(As Amended)

entered
12/9/02
amr

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231, on October 1, 2002.


Jeanette M. Saxton

AMENDMENT

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Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the Examiner's non-Final Office Action mailed July 1, 2002, please consider the following amendments and remarks in connection with the above-identified application.

IN THE SPECIFICATION:

On page 3, please replace the first full paragraph with the following substitute paragraph.

Attached hereto is a marked-up copy of the substitute paragraph.

Next, as shown in FIG. 8D, with the gate electrode 103 and the sidewall 106 used as a